

Data Sheet November 1999 File Number 2903.4

100MHz, High Input Impedance, Very Wideband, Uncompensated Operational Amplifiers

HA-2620/2625 are bipolar operational amplifiers that feature very high input impedance (500M Ω , HA-2620) coupled with wideband AC performance. The high resistance of the input stage is complemented by low offset voltage (0.5mV, HA-2620) and low bias and offset current (1nA, HA-2620) to facilitate accurate signal processing. Input offset can be reduced further by means of an external nulling potentiometer. The 100MHz gain bandwidth product (HA-2620/2625 are stable for closed loop gains greater than 5), 35V/µs slew rate and 150kV/V open loop gain enables HA-2620/2625 to perform high gain amplification of very fast, wideband signals. These dynamic characteristics, coupled with fast settling times, make these amplifiers ideally suited to pulse amplification designs as well as high frequency (e.g., video) applications. The frequency response of the amplifier can be tailored to exact design requirements by means of an external bandwidth control capacitor connected from the Comp pin to GND.

In addition to its application in pulse and video amplifier designs, HA-2620/2625 is particularly suited to other high performance designs such as high-gain low distortion audio amplifiers, high-Q and wideband active filters and high-speed comparators. For more information, please refer to Application Notes AN509, AN519 and AN546.

The HA-2620 is offered as /883 Military Grade. MIL-STD-883 data sheet is available upon request. Intersil AnswerFAX (321-724-7800) Document #3701.

Ordering Information

PART NUMBER (BRAND)	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
HA2-2620-2	-55 to 125	8 Pin Metal Can	T8.C
HA2-2625-5	0 to 75	8 Pin Metal Can	T8.C
HA3-2625-5	0 to 75	8 Ld PDIP	E8.3
HA9P2625-5 (H26255)	0 to 75	8 Ld SOIC	M8.15
HA9P2625-9 (H26259)	-40 to 85	8 Ld SOIC	M8.15

Features

• Gain Bandwidth Product $(A_V \ge 5) \dots 100MHz$
• High Input Impedance 500M Ω
Low Input Bias Current
Low Input Offset Current
Low Input Offset Voltage 0.5mV
• High Gain
• Slew Rate

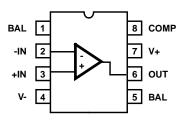
- · Output Short Circuit Protection
- · Compensation Pin for Unity Gain Capability

Applications

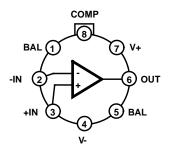
- Video and RF Amplifier
- Pulse Amplifier
- · Audio Amplifiers and Filters
- · High-Q Active Filters
- · High Speed Comparators
- · Low Distortion Oscillator

Pinouts

HA-2625 (PDIP, SOIC) TOP VIEW



HA-2620, HA-2625 (METAL CAN) TOP VIEW



Absolute Maximum Ratings

Supply Voltage (Between V+ and V- Terminals)	45V
Differential Input Voltage	12V
Peak Output Current Full Short Circuit Prote	ction

Operating Conditions

Temperature Range	
HA-2620-2	55°C to 125°C
HA-2625-5	0°C to 75°C
	40°C to 85°C

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (oC/W)	θ_{JC} (oC/W)
PDIP Package	117	N/A
SOIC Package	165	N/A
Metal Can Package	165	80
Maximum Junction Temperature (Hermetic I	Package)	175 ^o C
Maximum Junction Temperature (Plastic P	ackage)	150 ^o C
Maximum Storage Temperature Range	65	5°C to 150°C
Maximum Lead Temperature (Soldering 10	0s)	300°C
(SOIC - Lead Tips Only)		

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE

1. $\theta_{\mbox{\scriptsize JA}}$ is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications $V_{SUPPLY} = \pm 15V$, Unless Otherwise Specified

	TEMP.		HA-2620-2		HA-2625-5, -9			
PARAMETER	(°C)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
INPUT CHARACTERISTICS		•	'	'	•			'
Offset Voltage	25	-	0.5	4	-	3	5	mV
(Note 3)	Full	-	2	6	-	-	7	mV
Average Offset Voltage Drift	Full	-	5	-	-	5	-	μV/ ^o C
Bias Current	25	-	1	15	-	5	25	nA
	Full	-	10	35	-	-	40	nA
Offset Current	25		1	15	-	5	25	nA
	Full	-	5	35	-	-	40	nA
Differential Input Resistance (Note 2)	25	65	500	-	40	300	-	MΩ
Input Noise Voltage Density (f = 1kHz)	25	-	11	-	-	11	-	nV/√Hz
Input Noise Current Density (f = 1kHz)	25	-	0.16	-	-	0.16	-	pA/√Hz
Common Mode Range	Full	±11	±12	-	±11	±12	-	V
TRANSFER CHARACTERISTICS	3							
Large Signal Voltage Gain	25	100	150	-	80	150	-	kV/V
(Notes 4, 5)	Full	70	-	-	70	-	-	kV/V
Common Mode Rejection Ratio (Note 6)	Full	80	100	-	74	100	-	dB
Minimum Stable Gain	25	5	-	-	5	-	-	V/V
Gain Bandwidth Product (Notes 4, 7, 8)	25	-	100	-	-	100	-	MHz
OUTPUT CHARACTERISTICS								
Output Voltage Swing (Note 4)	Full	±10	±12	-	±10	±12	-	V
Output Current (Note 5)	25	±15	±22	-	±10	±18	-	mA
Full Power Bandwidth (Notes 4, 5, 9, 13)	25	400	600	-	320	600	-	kHz
TRANSIENT RESPONSE (Note	8)	1	1	1	1	1	1	1
Rise Time (Notes 4, 9, 10)	25	-	17	45	-	17	45	ns
Slew Rate (Notes 4, 9, 10, 12)	25	±25	±35	-	±20	±35	-	V/µs

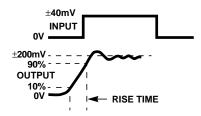
Electrical Specifications $V_{SUPPLY} = \pm 15V$, Unless Otherwise Specified (Continued)

	TEMP.	TEMP. HA-2620-2		HA-2625-5, -9				
PARAMETER	(°C)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
POWER SUPPLY CHARACTER	POWER SUPPLY CHARACTERISTICS							
Supply Current	25	-	3	3.7	-	3	4	mA
Power Supply Rejection Ratio (Note 11)	Full	80	90	-	74	90	-	dB

NOTES:

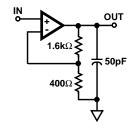
- 2. This parameter value guaranteed by design calculations.
- 3. Offset may be externally adjusted to zero.
- 4. $R_L = 2k\Omega$.
- 5. $V_{OUT} = \pm 10V$.
- 6. $V_{CM} = \pm 10V$.
- 7. $V_{OUT} < 90$ mV.
- 8. 40dB Gain.
- 9. See Transient Response Test Circuits and Waveforms.
- 10. A_V = 5 (The HA-2620 family is not stable at unity gain without external compensation).
- 11. $\Delta V_S = \pm 5V$.
- 12. $V_{OUT} = \pm 5V$.
- 13. Full Power Bandwidth guaranteed by slew rate measurement: FPBW = $\frac{\text{Slew Rate}}{2\pi V_{\text{PFAK}}}$

Test Circuits and Waveforms



NOTE: Measured on both positive and negative transitions from 0V to +200mV and 0V to -200mV at output.

TRANSIENT RESPONSE



V+ 0 100kΩ 0W0 0N 0 OUT

SLEW RATE

NOTE: Tested Offset Adjustment is $|V_{OS} + 1mV|$ minimum referred to output. Typical range is $\pm 10mV$ with $R_T = 100k\Omega$.

SUGGESTED V_{OS} ADJUSTMENT AND COMPENSATION HOOK-UP

SLEW RATE

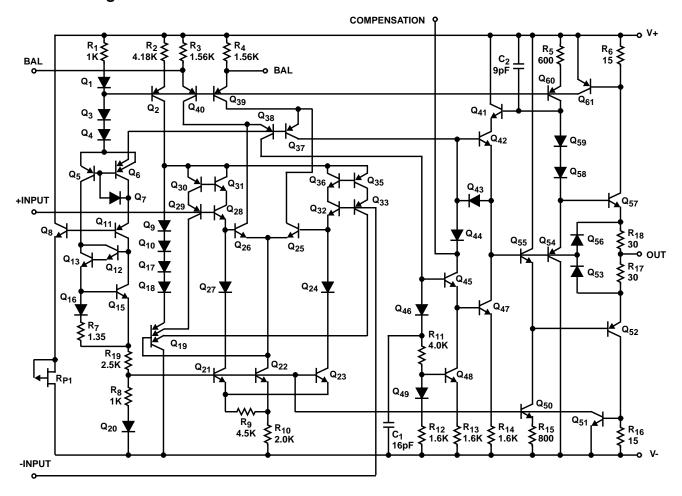
1V

INPUT

-1V = +5V -90% -

OUTPUT

Schematic Diagram



Typical Applications

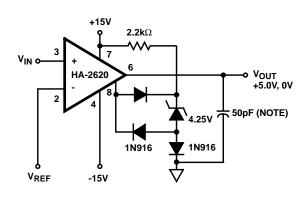


FIGURE 1. HIGH INPUT IMPEDANCE COMPARATOR

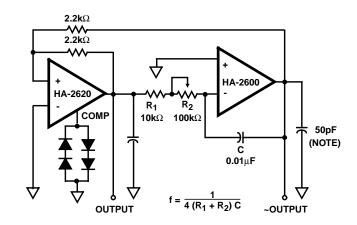
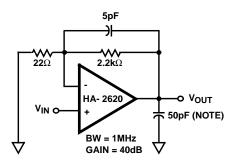


FIGURE 2. FUNCTION GENERATOR

Typical Applications (Continued)



NOTE: A small load capacitance of at least 30pF (including stray capacitance) is recommended to prevent possible high frequency oscillations.

FIGURE 3. VIDEO AMPLIFIER

$\textit{Typical Performance Curves} \quad \text{V}_{\text{S}} = \pm 15 \text{V}, \, \text{T}_{\text{A}} = 25^{\text{O}} \text{C}, \, \text{Unless Otherwise Specified}$

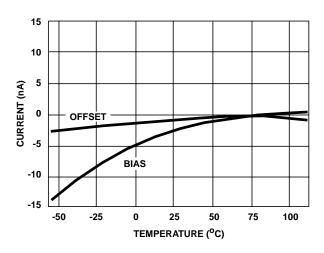


FIGURE 4. INPUT BIAS CURRENT AND OFFSET CURRENT VS TEMPERATURE

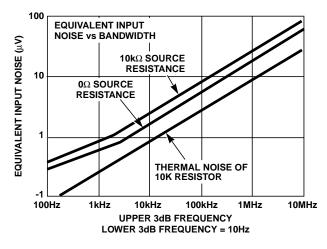


FIGURE 5. BROADBAND NOISE CHARACTERISTICS

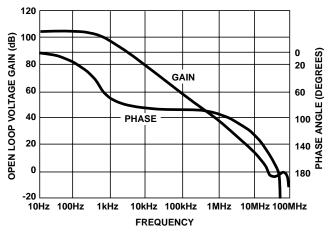


FIGURE 6. OPEN LOOP FREQUENCY RESPONSE

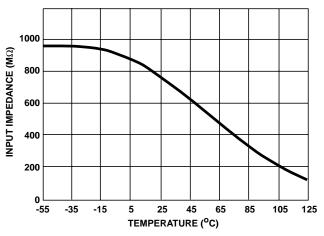


FIGURE 7. INPUT IMPEDANCE vs TEMPERATURE, 100Hz

$\textit{Typical Performance Curves} \quad \text{V}_{\text{S}} = \pm 15 \text{V}, \, \text{T}_{\text{A}} = 25^{\text{O}} \text{C}, \, \text{Unless Otherwise Specified (Continued)}$

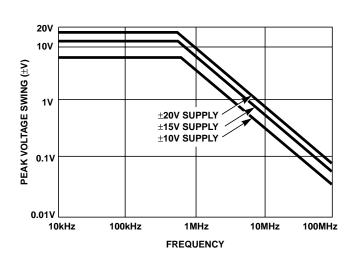


FIGURE 8. OUTPUT VOLTAGE SWING vs FREQUENCY

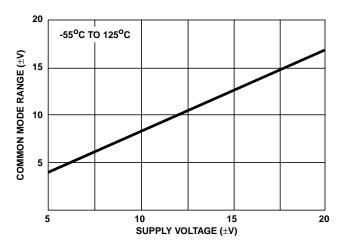
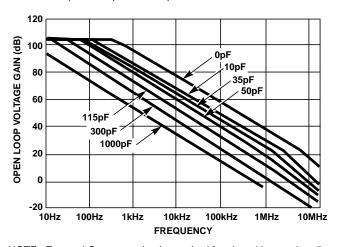


FIGURE 10. COMMON MODE VOLTAGE RANGE vs SUPPLY VOLTAGE



NOTE: External Compensation is required for closed loop gain < 5. If external compensation is used, also connect 100pF capacitor from output to ground.

FIGURE 9. OPEN LOOP FREQUENCY RESPONSE FOR VARIOUS VALUES OF CAPACITORS FROM COMP. PIN TO GND

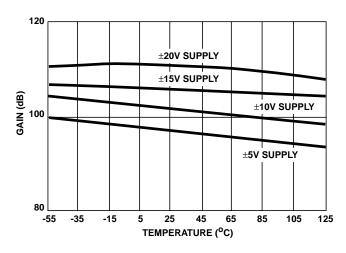


FIGURE 11. OPEN LOOP VOLTAGE GAIN vs TEMPERATURE

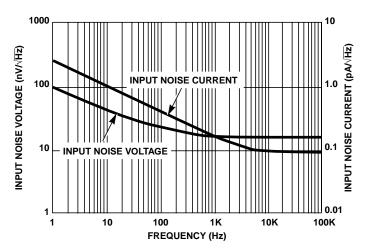


FIGURE 12. NOISE DENSITY vs FREQUENCY

Die Characteristics

DIE DIMENSIONS:

69 mils x 56 mils x 19 mils 1750μm x 1420μm x 483μm

METALLIZATION:

Type: AI, 1% Cu Thickness: 16kÅ ±2kÅ

SUBSTRATE POTENTIAL (POWERED UP):

Unbiased

Metallization Mask Layout

PASSIVATION:

Type: Nitride (Si_3N_4) over Silox $(SiO_2, 5\% Phos.)$

Silox Thickness: 12kÅ ±2kÅ Nitride Thickness: 3.5kÅ ±1.5kÅ

TRANSISTOR COUNT:

140

PROCESS:

Bipolar Dielectric Isolation

HA-2620, HA-2625

BAL

BAL

IN

HIN

V
COMP

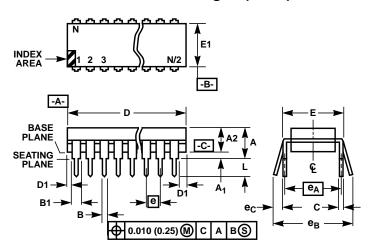
V+

OUT

BAL

V
DATE OF THE PART OF

Dual-In-Line Plastic Packages (PDIP)



NOTES:

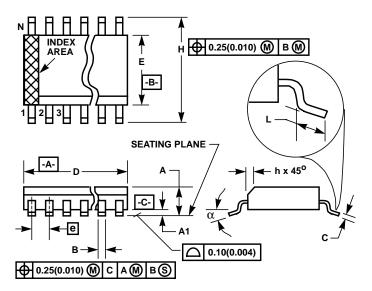
- Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- E and eA are measured with the leads constrained to be perpendicular to datum -C-.
- 7. e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- 8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- 9. N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

E8.3 (JEDEC MS-001-BA ISSUE D) 8 LEAD DUAL-IN-LINE PLASTIC PACKAGE

	INC	HES	MILLIM		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
А	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
В	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8, 10
С	0.008	0.014	0.204	0.355	-
D	0.355	0.400	9.01	10.16	5
D1	0.005	-	0.13	-	5
Е	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
е	0.100	BSC	2.54 BSC		-
e _A	0.300	0.300 BSC		7.62 BSC	
e _B	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	8	3	8	3	9

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Small Outline Plastic Packages (SOIC)



NOTES:

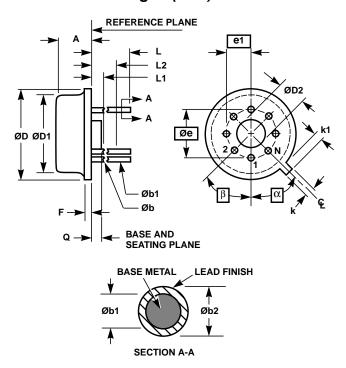
- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M8.15 (JEDEC MS-012-AA ISSUE C) 8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE

	INCHES		MILLIM		
SYMBOL	MIN MAX		MIN	MAX	NOTES
А	0.0532	0.0688	1.35	1.75	-
A1	0.0040	0.0098	0.10	0.25	-
В	0.013	0.020	0.33	0.51	9
С	0.0075	0.0098	0.19	0.25	-
D	0.1890	0.1968	4.80	5.00	3
Е	0.1497	0.1574	3.80	4.00	4
е	0.050	BSC	1.27 BSC		-
Н	0.2284	0.2440	5.80	6.20	-
h	0.0099	0.0196	0.25	0.50	5
L	0.016	0.050	0.40	1.27	6
N	8		8	3	7
α	0°	8 ⁰	0°	8º	-

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Metal Can Packages (Can)



NOTES:

- (All leads) Øb applies between L1 and L2. Øb1 applies between L2 and 0.500 from the reference plane. Diameter is uncontrolled in L1 and beyond 0.500 from the reference plane.
- 2. Measured from maximum diameter of the product.
- 3. α is the basic spacing from the centerline of the tab to terminal 1 and β is the basic spacing of each lead or lead position (N -1 places) from α , looking at the bottom of the package.
- 4. N is the maximum number of terminal positions.
- 5. Dimensioning and tolerancing per ANSI Y14.5M 1982.
- 6. Controlling dimension: INCH.

T8.C MIL-STD-1835 MACY1-X8 (A1) 8 LEAD METAL CAN PACKAGE

	INCHES		MILLIM	MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	NOTES	
Α	0.165	0.185	4.19	4.70	-	
Øb	0.016	0.019	0.41	0.48	1	
Øb1	0.016	0.021	0.41	0.53	1	
Øb2	0.016	0.024	0.41	0.61	-	
ØD	0.335	0.375	8.51	9.40	-	
ØD1	0.305	0.335	7.75	8.51	-	
ØD2	0.110	0.160	2.79	4.06	-	
е	0.200	BSC	5.08 BSC		-	
e1	0.100	BSC	2.54 BSC		-	
F	-	0.040	-	1.02	-	
k	0.027	0.034	0.69	0.86	-	
k1	0.027	0.045	0.69	1.14	2	
L	0.500	0.750	12.70	19.05	1	
L1	-	0.050	-	1.27	1	
L2	0.250	-	6.35	-	1	
Q	0.010	0.045	0.25	1.14	-	
α	45° BSC		45° BSC		3	
β	45° BSC		45° BSC		3	
N	8	3	3	3	4	

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